SN54AHC244, SN74AHC244 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCL5226H – OCTOBER 1995 – REVISED JANUARY 2000

- *EPIC*TM (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

These octal buffers/drivers are designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The 'AHC244 devices are organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHC244 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74AHC244 is characterized for operation from -40° C to 85°C.

FUNCTION TABLE (each 4-bit buffer/driver)

INPU	JTS	OUTPUT						
OE	Α	Y						
L	Н	Н						
L	L	L						
н	Х	Z						



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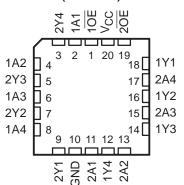
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SN54AHC244 J OR W PACKAGE
SN74AHC244 DB, DGV, DW, N, OR PW PACKAGE
(TOP VIEW)

	(101	vi L vv)	
1OE [1A1 [2Y4 [1A2 [2Y3 [1A3 [2Y2 [1A4 [2Y1]	2 3 4 5 6 7 8	20 19 18 17 16 15 14 13] V _{CC}] 2OE] 1Y1] 2A4] 1Y2] 2A3] 1Y3] 2A2] 1Y4
2Y1 [] 1Y4
2Y1 [9] 1Y4
GND [10	11] 2A1

SN54AHC244 ... FK PACKAGE (TOP VIEW)



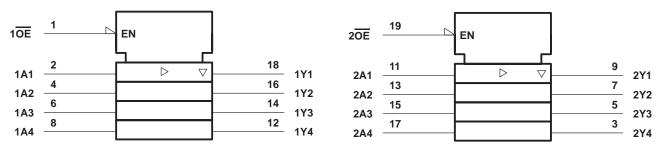
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processing does not necessarily include testing of all parameters.

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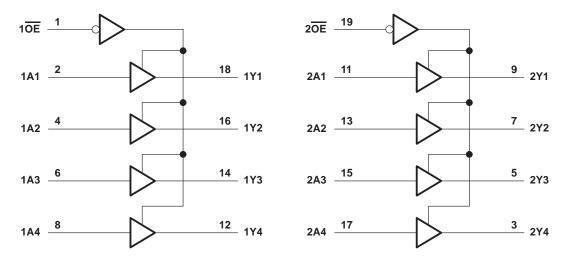
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)		
Output voltage range, V _O (see Note 1)		
Input clamp current, I _{IK} (V _I < 0)		
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{CC}	;)	±20 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$		
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ_{JA} (see Note 2):	DB package	70°C/W
	DGV package	92°C/W
	DW package	58°C/W
	N package	69°C/W
	PW package	83°C/W
Storage temperature range, T _{stg}		. −65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 3)

			SN54A	SN54AHC244		N54AHC244 SN74AHC244			LINUT
			MIN	MAX	MIN MAX		UNIT		
Vcc	Supply voltage		2	5.5	2	5.5	V		
		$V_{CC} = 2 V$	1.5		1.5				
VIH	High-level input voltage	$V_{CC} = 3 V$	2.1		2.1		V		
		V _{CC} = 5.5 V	3.85		3.85				
		V _{CC} = 2 V		0.5		0.5			
VIL	Low-level input voltage	$V_{CC} = 3 V$		0.9		0.9	V		
		V _{CC} = 5.5 V		1.65		1.65			
VI	Input voltage	-	0	5.5	0	5.5	V		
Vo	Output voltage		0	VCC	0	VCC	V		
	High-level output current	$V_{CC} = 2 V$		-50		-50	μA		
ЮН		V_{CC} = 3.3 V ± 0.3 V		-4		-4	mA		
		V_{CC} = 5 V ± 0.5 V		-8		-8	mA		
		$V_{CC} = 2 V$		50		50	μΑ		
IOL	Low-level output current	V_{CC} = 3.3 V ± 0.3 V		4		4	mA		
		V_{CC} = 5 V ± 0.5 V		8		8	mA		
A # / A	longit transition rise or fell rate	V_{CC} = 3.3 V ± 0.3 V		100		100	20/1		
$\Delta t / \Delta v$	Input transition rise or fall rate	V_{CC} = 5 V ± 0.5 V		20		20	ns/V		
TA	Operating free-air temperature		-55	125	-40	85	°C		

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	Т	₄ = 25°C	;	SN54AHC244		SN74AHC244		UNIT
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	1.9	2		1.9		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		2.9		
∨он		4.5 V	4.4	4.5		4.4		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
		2 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
VOL		4.5 V			0.1		0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
li li	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1*		±1	μA
loz	$V_O = V_{CC}$ or GND, VI (OE) = VIL or VIH	5.5 V			±0.25		±2.5		±2.5	μΑ
ICC	$V_{I} = V_{CC} \text{ or GND}, \qquad I_{O} = 0$	5.5 V			4		40		40	μΑ
Ci	$V_I = V_{CC}$ or GND	5 V		2	10				10	pF
Co	$V_{O} = V_{CC} \text{ or } GND$	5 V		3.5						pF

* On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 V$.



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

00	•		, (-	-						
	FROM	то	LOAD	Τ ₄	ς = 25°C	;	SN54A	HC244	SN74A	HC244	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	А	Y	C _I = 15 pF		5.8*	8.4*	1*	10*	1	10	20
^t PHL	A	T	CL = 15 pr		5.8*	8.4*	1*	10*	1	10	ns
^t PZH	OE	Y	C _L = 15 pF		6.6*	10.6*	1*	12.5*	1	12.5	ns
^t PZL	OE	T	CL = 15 pr		6.6*	10.6*	1*	12.5*	1	12.5	115
^t PHZ	OE	Y	C _L = 15 pF		5*	9.7*	1*	11*	1	11	ns
^t PLZ		T	CL = 15 pr		5*	9.7*	1*	11*	1	11	115
^t PLH	А	Y	C _I = 50 pF		8.3	11.9	1	13.5	1	13.5	ns
t _{PHL}	~	I	CL = 30 pr		8.3	11.9	1	13.5	1	13.5	115
^t PZH	OE	Y	C _I = 50 pF		9.1	14.1	1	16	1	16	ns
^t PZL	OE	I	CL = 30 pr		9.1	14.1	1	16	1	16	115
^t PHZ	OE	Y	C _I = 50 pF		10.3	14	1	16	1	16	ns
t _{PLZ}		ſ	CL = 50 pr		10.3	14	1	16	1	16	115
^t sk(o)			C _L = 50 pF			1.5**				1.5	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

** On products compliant to MIL-PRF-38535, this parameter does not apply.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	Т	₄ = 25°C	;	SN54A	HC244	SN74A	HC244	LINUT
PARAMETER	(INPUT)	(OUTPUT)			TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	А	Y	C _I = 15 pF		3.9*	5.5*	1*	6.5*	1	6.5	ns
^t PHL	A	T	CL = 15 pr		3.9*	5.5*	1*	6.5*	1	6.5	115
^t PZH	OE	Y	C _I = 15 pF		4.7*	7.3*	1*	8.5*	1	8.5	ns
^t PZL	ÛE	I	CL = 15 pr		4.7*	7.3*	1*	8.5*	1	8.5	115
^t PHZ	OE	Y	C _I = 15 pF		5*	7.2*	1*	8.5*	1	8.5	ns
^t PLZ	ÛE	I	CL = 15 pr		5*	7.2*	1*	8.5*	1	8.5	115
^t PLH	А	Y	C _I = 50 pF		5.4	7.5	1	8.5	1	8.5	ns
^t PHL	~	I	0L = 30 pi		5.4	7.5	1	8.5	1	8.5	115
^t PZH	ŌĒ	Y	C _L = 50 pF		6.2	9.3	1	10.5	1	10.5	ns
^t PZL		I	0L = 30 pi		6.2	9.3	1	10.5	1	10.5	115
^t PHZ	OE	Y	$C_{I} = 50 pF$		6.7	9.2	1	10.5	1	10.5	ns
^t PLZ		1	0L = 30 pr		6.7	9.2	1	10.5	1	10.5	115
^t sk(o)			CL = 50 pF			1**				1	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

** On products compliant to MIL-PRF-38535, this parameter does not apply.



noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25^{\circ}C (see Note 4)

	PARAMETER		SN74AHC244				
	FARAMETER	MIN TYP MAX 0.5 -0.2 4.8 3.5	UNIT				
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5		V		
VOL(V)	Quiet output, minimum dynamic V _{OL}		-0.2		V		
VOH(V)	Quiet output, minimum dynamic V _{OH}		4.8		V		
VIH(D)	High-level dynamic input voltage	3.5			V		
V _{IL(D)}	Low-level dynamic input voltage			1.5	V		

NOTE 4: Characteristics are for surface-mount packages only.

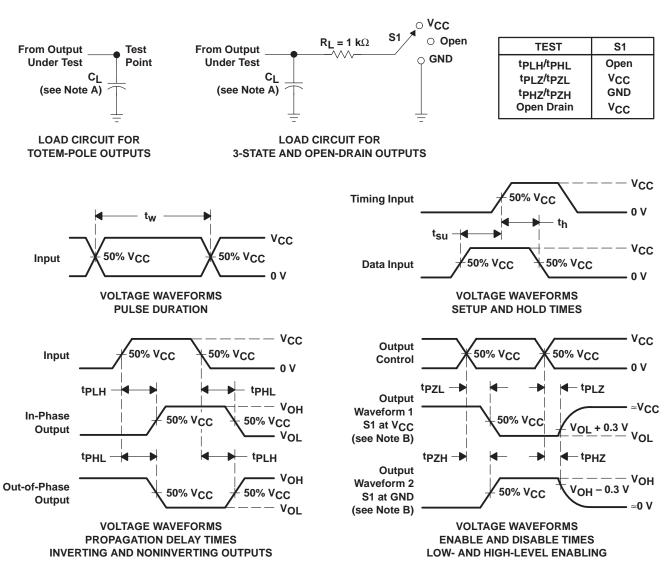
operating characteristics, V_{CC} = 5 V, T_A = 25° C

PARAMETER		TEST CO	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	8.6	pF



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_Q = 50 Ω , t_f \leq 3 ns, t_f \leq 3 ns.

D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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